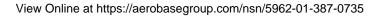
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Memory Microcircuit - Page 1 of 1



# Storage Tempurature Range:

-55.0/+125.0 degrees celsius

# **Features Provided:**

Burn in, mil-std-883, class b

#### Output Logic Form:

Complementary-metal oxide-semiconductor logic

# Voltage Rating And Type Per Characteristic:

5.0 volts total supply

### **Time Rating Per Chacteristic:**

250.00 nanoseconds access

### Memory Device Type:

Eeprom

# Terminal Type And Quantity:

28 leadless

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

# Fiig:

A458a0

